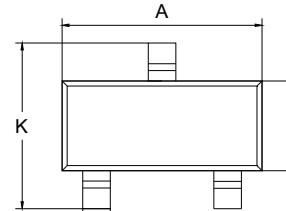


FEATURES

- Epitaxial planar die construction.
- Also available in lead free version.

APPLICATIONS

- High current surface mount PNP silicon switching transistor for load management in portable applications.



SOT-23		
Dim	Min	Max
A	2.70	3.10
B	1.10	1.50
C	1.0 Typical	
D	0.4 Typical	
E	0.35	0.48
G	1.80	2.00
H	0.02	0.1
J	0.1 Typical	
K	2.20	2.60

All Dimensions in mm

ORDERING INFORMATION

Type No.	Marking	Package Code
MMBT589	589	SOT-23

MAXIMUM RATING @ Ta=25°C unless otherwise specified

Symbol	Parameter	Value	UNIT
V _{CBO}	collector-base voltage	-50	V
V _{CEO}	collector-emitter voltage	-30	V
V _{EBO}	emitter-base voltage	-5	V
I _C	collector current (DC)	-1.0	A
I _{CM}	Collector Current-Peak	-2.0	A
P _C	Collector dissipation	0.31	W
R _{θJA}	Thermal Resistance, Junction to Ambient	403	°C/W
T _j , T _{stg}	junction and storage temperature	-55 to +150	°C

ELECTRICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified

Symbol	Parameter	Test conditions	MIN.	MAX.	UNIT
V _{(BR)CBO}	Collector-base breakdown voltage	I _C =-100μA, I _E =0	-50		V
V _{(BR)CEO}	Collector-emitter breakdown voltage	I _C =-10mA, I _B =0	-30		V
V _{(BR)EBO}	Emitter-base breakdown voltage	I _E =-100μA, I _C =0	-5		V
I _{CBO}	Collector cut-off current	I _E = 0; V _{CB} = -30V	-	-0.1	μA
I _{CES}	Collector-emitter cutoff current	V _{CES} =-30V	-	-0.1	μA
I _{EBO}	Emitter cut-off current	I _C = 0; V _{EB} = -4V	-	-0.1	μA
h _{FE}	DC current gain	V _{CE} = -2V; I _C = -1mA	100	-	
		V _{CE} = -2V; I _C = -500mA	100	300	
		V _{CE} = -2V; I _C = -1.0A	80	-	
		V _{CE} = -2V; I _C = -2.0A	40	-	
V _{CE(sat)}	collector-emitter saturation voltage	I _C = -0.5A; I _B = -0.05A	-	-0.25	
		I _C = -1.0A; I _B = -0.1A	-	-0.30	V
		I _C = -2.0A; I _B = -0.2A	-	-0.65	
V _{BE(sat)}	base-emitter saturation voltage	I _C = -1.0A; I _B = -0.1A	-	-1.2	V
V _{BE(on)}	Base-emitter Turn-on voltage	I _C =-1.0A, V _{CE} =-2.0V	-	-1.1	V
f _T	transition frequency	I _C = -100mA; V _{CE} = -5V; f = 100MHz	100	-	MHz
C _{obo}	Output capacitance	f=1.0MHz	-	15	pF

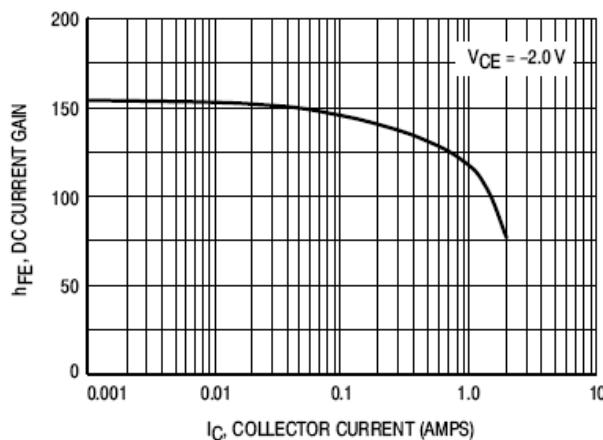

TYPICAL CHARACTERISTICS @ $T_a=25^\circ\text{C}$ unless otherwise specified


Figure 1. DC Current Gain versus
Collector Current

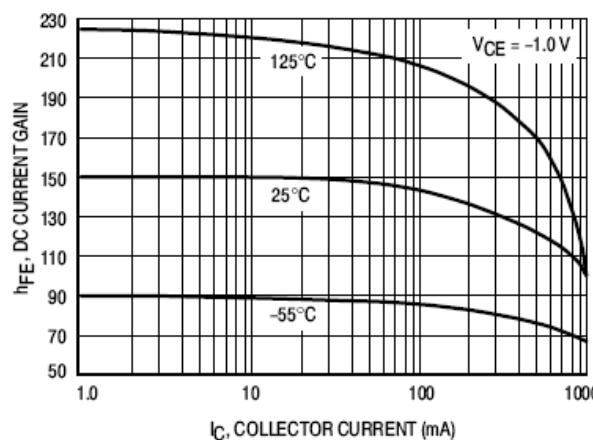


Figure 2. DC Current Gain versus
Collector Current

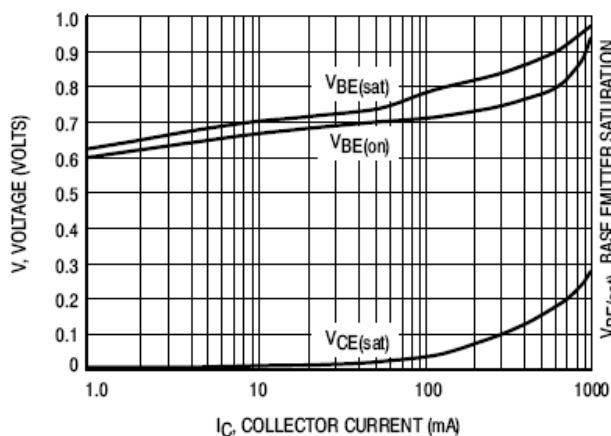


Figure 3. "On" Voltages

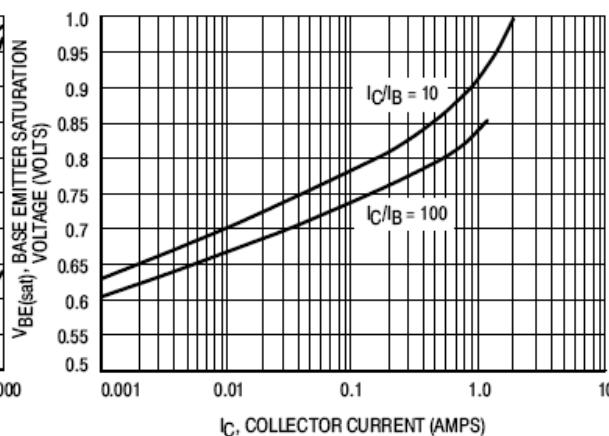


Figure 4. Base Emitter Saturation Voltage
versus Collector Current

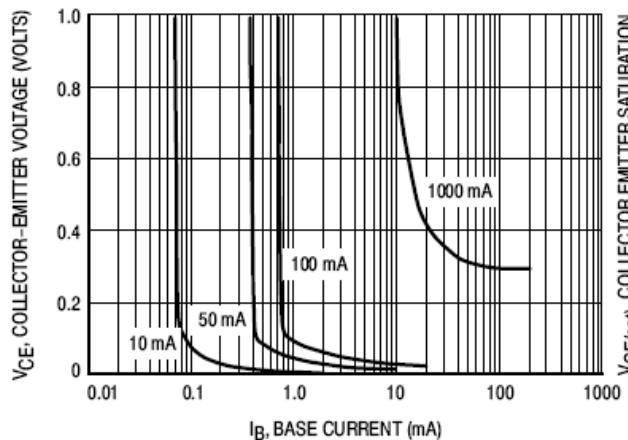


Figure 5. Collector Emitter Saturation Voltage versus Collector Current

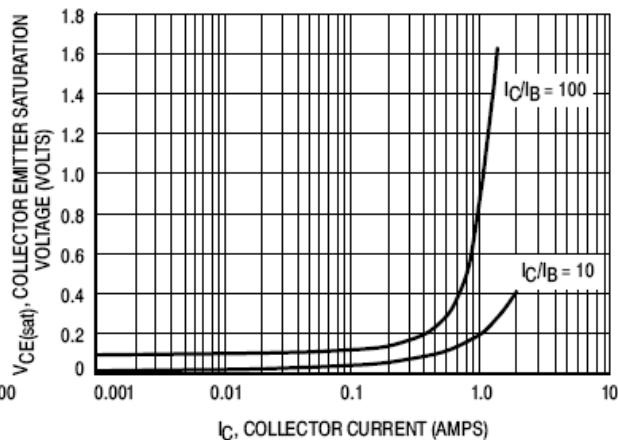


Figure 6. Collector Emitter Saturation Voltage versus Collector Current

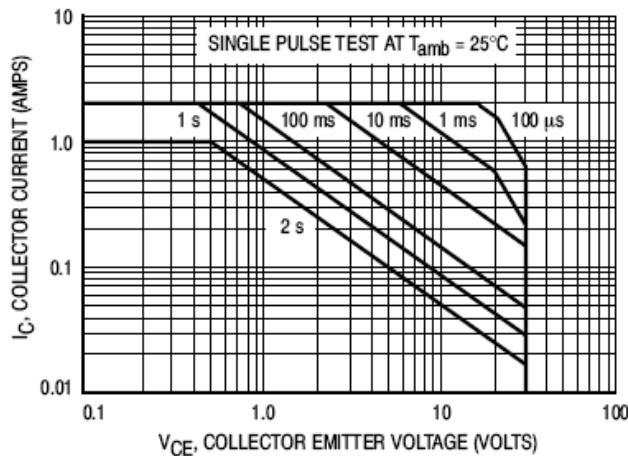


Figure 7. Safe Operating Area

Package	Reel	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)
SOT-23	3000pcs	7inch	45,000pcs	203×203×195	180,000pcs	438×438×220